

Rail-to-Rail Input/Output, 10 MHz Op Amps

1. Description

This production is wideband, low-noise, low-distortion dual operational amplifier, that offer rail-to-rail inputs/outputs and single supply operation down to 2.2V. They draw 1.6mA of quiescent supply current while featuring ultra-low distortion (0.0002% THD+N), as well as low input voltage-noise density (15nV/Hz) and low input current noise density (0.5fA/Hz). These features make the devices an ideal choice for applications that require low distortion and/or low noise.

These amplifiers have inputs and outputs which swing rail-to-rail and their input common mode voltage range includes ground. The maximum input offset of these amplifiers is less than 5mV.

This production is unity gain stable with a gain-band width of 10MHz. The extended temperature range of -40°C to +125°C over all supply voltages offers additional design flexibility.

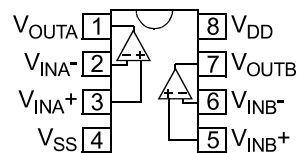
2. Features

- Single-Supply Operation from +2.2V ~ +5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 10MHz (Typ.)
- Low Input Bias Current: 10pA (Typ.)
- Low Offset Voltage: 5mV (Max.)
- Quiescent Current: 800µA per Amplifier (Typ.)
- Operating Temperature: -40°C to +125°C

3. Applications

- Portable Equipment
- Mobile Communications
- Smoke Detector
- Sensor Interface
- Medical Instrumentation

4. Pinning Configuration



5. Ordering Information

Type Number	Package Type	Packing
MCP6022T-I/SN	SOIC-8	Tape & Reel
MCP6022T-E/SN	SOIC-8	Tape & Reel
MCP6022T-I/ST	TSSOP-8	Tape & Reel
MCP6022T-E/ST	TSSOP-8	Tape & Reel
MCP6022-I/P	DIP-8	Tube
MCP6022-E/P	DIP-8	Tube

Note: If the physical information is inconsistent with the ordering information, please refer to the actual product.

6. Absolute Maximum Ratings

Condition	Min	Max
Power Supply Voltage (V_{DD} to V_{SS})	-0.5V	+7V
Analog Input Voltage (IN+ or IN-)	$V_{SS}-0.5V$	$V_{+}+0.5V$
PDB Input Voltage	$V_{SS}-0.5V$	+7V
Operating Temperature Range	-40°C	+125°C
Junction Temperature	+150°C	
Storage Temperature Range	-65°C	+150°C
Lead Temperature (soldering, 10sec)	+300°C	
Package Thermal Resistance ($T_A=+25^{\circ}C$)		

7. Electrical Characteristics

($V_{DD} = +5V$, $V_{SS} = 0V$, $V_{CM} = 0V$, $V_{OUT} = V_{DD}/2$, $R_L = 100k\Omega$ tied to $V_{DD}/2$, $SHDNB = V_{DD}$, $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$) (Notes 1)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Supply Voltage Range	V_{DD}	Guaranteed by the PSRR test	2.2		5.5	V
Quiescent Supply Current (per Amplifier)	I_{DD}	$V_{DD} = 3V$		0.8		mA
		$V_{DD} = 5V$		0.8	1.2	
Input Offset Voltage	V_{OS}	$T_A = 25^{\circ}C$			± 5	mV
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$				
		$T_A = -40^{\circ}C$ to $+125^{\circ}C$			± 1.5	
Input Offset Voltage Tempco	$\Delta V_{OS}/\Delta T$			± 0.3	± 6	$\mu V / ^{\circ}C$
Input Bias Current	I_B	(Note 3)		± 1	± 100	pA
Input Offset Current	I_{OS}	(Note 3)		± 1	± 100	pA
Input Common-Mode Voltage Range	V_{CM}	Guaranteed by the $T_A = -40^{\circ}C$ to $+125^{\circ}C$	-		$V_{OO}+0.2$	V
		CMRR test $T_A = -40^{\circ}C$ to $+125^{\circ}C$	0.2		V_{DD}	
Common-Mode Rejection Ratio	CMRR	$V_{SS}-0.2V \leq V_{CM} \leq V_{DD}+0.2V$ $T_A = 25^{\circ}C$		75		dB
		$V_{SS} \leq V_{CM} \leq 5V$ $T_A = +25^{\circ}C$	65	80		
		$V_{SS}-0.2V \leq V_{CM} \leq V_{DD}+0.2V$ $T_A = -40^{\circ}C$ to $+125^{\circ}C$		65		
Power-Supply Rejection Ratio	PSRR	$V_{DD} = +2.2V$ to $+5.5V$	75	90		dB
Open-Loop Voltage Gain	A_V	$R_L = 100k\Omega$ to $V_{DD}/2$, $100mV \leq V_O \leq V_{DD} - 125mV$	90	100		dB
		$R_L = 1k\Omega$ to $V_{DD}/2$, $200mV \leq V_O \leq V_{DD} - 250mV$	75	85		
		$R_L = 500\Omega$ to $V_{DD}/2$, $350mV \leq V_O \leq V_{DD} - 500mV$	55	65		

Output Voltage Swing	V_{OUT}	$ V_{IN+} - V_{IN-} \geq 10\text{mV}$ $V_{DD} - V_{OH}$		10	35	mV
		$R_L = 10\text{k}\Omega$ to $V_{DD}/2$ $V_{OL} - V_{SS}$		10	30	
		$ V_{IN+} - V_{IN-} \geq 10\text{mV}$ $V_{DD} - V_{OH}$		80	200	
		$R_L = 1\text{k}\Omega$ to $V_{DD}/2$ $V_{OL} - V_{SS}$		50	150	
		$ V_{IN+} - V_{IN-} \geq 10\text{mV}$ $V_{DD} - V_{OH}$		100	350	
		$R_L = 500\Omega$ to $V_{DD}/2$ $V_{OL} - V_{SS}$		80	260	
Output Short-Circuit Current	I_{SC}	Sinking or Sourcing		± 50		mA
PDB Logic Low	V_{IL}				0.8	V
PDB Logic High	V_{IH}		2			V
Turn-On Time	T_{ON}			2.2		μs
Turn-Off Time	T_{OFF}			0.8		μs
Output Leakage Current	I_{LEAK}	Shutdown Mode (PDB = V_{SS}), $V_{OUT} = V_{SS}$ to V_{DD}		± 0.001	± 1.0	μA
Input Capacitance	C_{IN}			10		pF
Gain Bandwidth Product	GBW	$A_V = +1V/V$		10		MHz
Slew Rate	SR	$A_V = +1V/V$		4.5		V/ μs
Full Power Bandwidth		$A_V = +1V/V$		0.4		MHz
Phase Margin	Φ_m	$A_V = +1V/V$		55		deg
Gain Margin	G_m	$A_V = +1V/V$		12		dB
Settling Time	t_s	To 0.01%, $V_{OUT} = 2\text{V}$ step $A_V = +1V/V$		1		μs
Capacitive-Load Stability	C_{LOAD}	No sustained oscillations. $A_V = +1V/V$		200		pF
Peak-to-Peak Input Noise Voltage (Note 5)	$e_n(p-p)$	$f = 0.1\text{Hz}$ to 10Hz		5		$\mu\text{Vp-p}$
Input Voltage Noise Density	e_n	$f = 10\text{Hz}$		60		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1\text{kHz}$		30		
		$f = 30\text{kHz}$		15		
Input Current Noise Density	I_n	$f = 1\text{kHz}$				$\text{fA}/\sqrt{\text{Hz}}$
Total Harmonic Distortion plus Noise	THD+N	$V_{OUT} = 2\text{Vp-p}$,				%
		$A_V = +1V/V$, $f = 1\text{kHz}$		0.0001		
		$R_L = 10\text{k}\Omega$ to GND $f = 20\text{kHz}$		0.002		
		$V_{OUT} = 2\text{Vp-p}$,				

	$A_V = +1V/V, f = 1kHz$	0.0002	
	$RL = 1k\Omega \text{ to GND } f = 20kHz$	0.004	

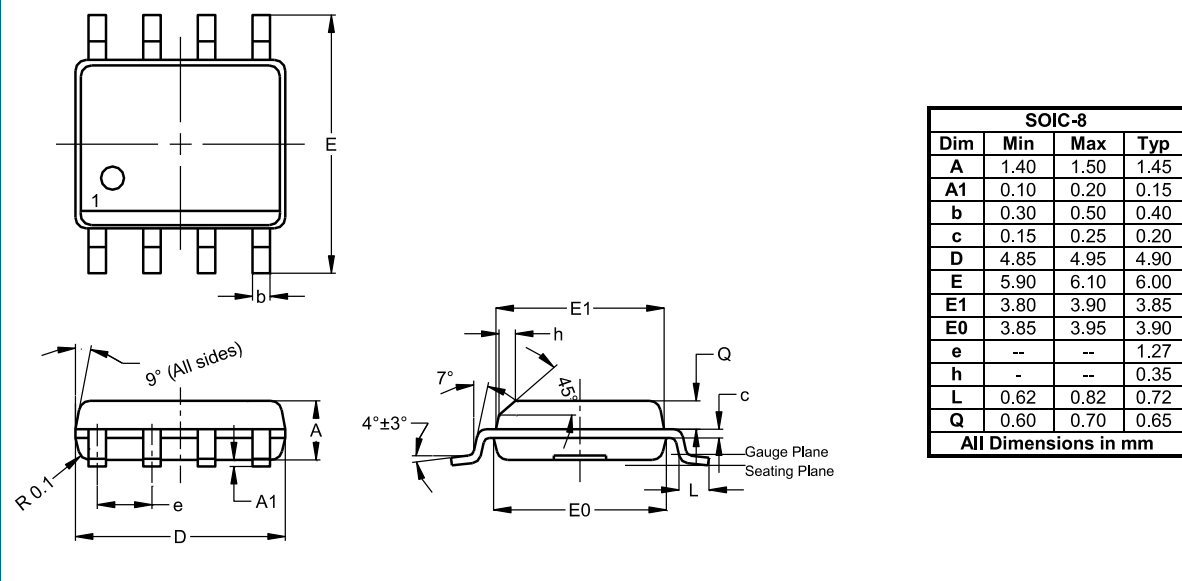
Note1: All devices are 100% production tested at $T_A = +25^\circ C$, all specifications over the automotive temperature range are guaranteed by design, not production tested.

Note2: Parameter is guaranteed by design.

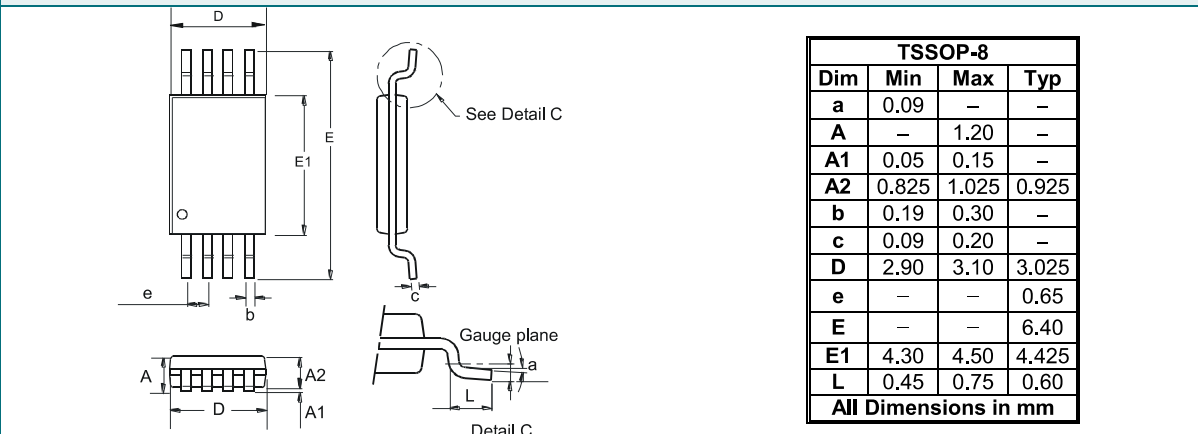
Note3: Peak-to-peak input noise voltage is defined as six times RMS value of input noise voltage

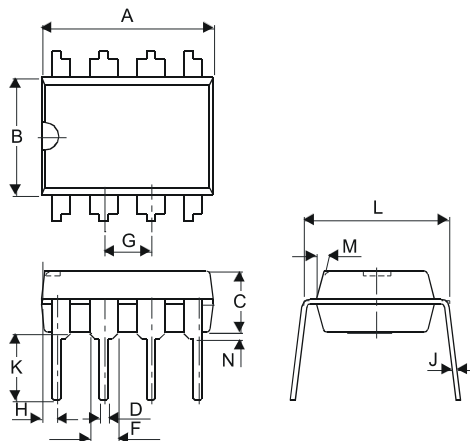
8. Package Outlines

SOIC-8



TSSOP-8



DIP-8


PDIP-8		
Dim	Min	Max
A	9.02	9.53
B	6.15	6.35
C	3.10	3.50
D	0.36	0.56
F	1.40	1.65
G	2.54 typ.	
H	0.71	0.97
J	0.20	0.36
K	2.92	3.81
L	7.62	8.26
M	-	15°
N	0.38 (min)	
All Dimensions in mm		

9. Disclaimers

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